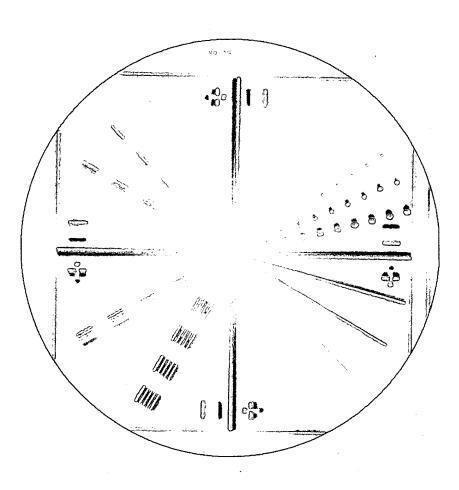
## CPD Scanning Overview

Scanning for Surface Measurements Contact Potential Difference

#### Unique Sensor for Imaging of Geometry and Chemistry

- High-speed, non-contact, non-destructive detection of surface chemistry and geometry.
- High resolution imaging at speeds suitable for real-time process control.
- Adaptable to a variety of configurations and applications.

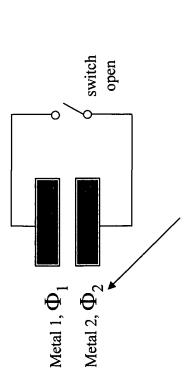


#### Theoretical Concept of Contact Potential Difference

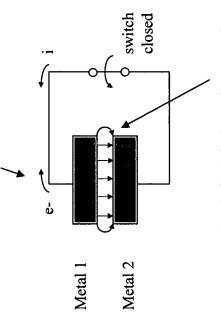
Contact Potential Difference (CPD) is the difference in surface potential that is created when two dissimilar materials (e.g. metals) are electrically connected.

Electrons flow to equilibrate their

energies.

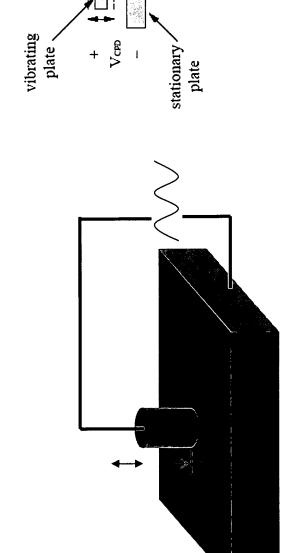


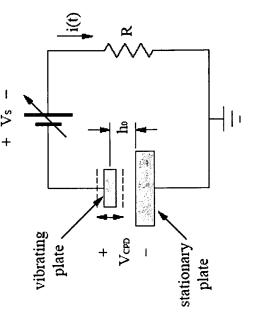
Surface Potential: prevents electrons from 'spilling' out of the bulk.



Electrical field develops when the switch is closed

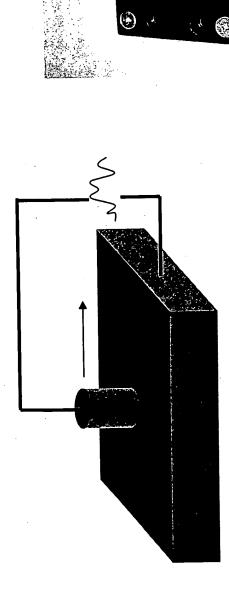
#### Prior Technology: Vibrating Kelvin Probe

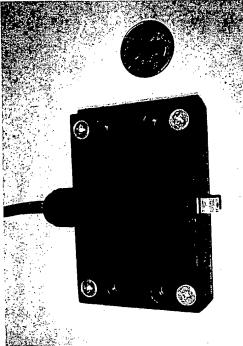


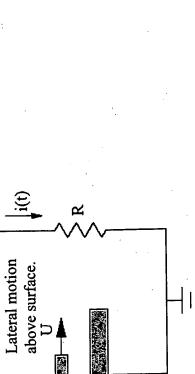




## Scanning CPD Sensor

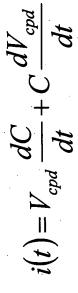




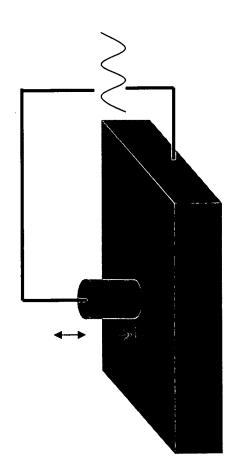


 $V_{cpd}^+(t)$ 

CPD probe tip



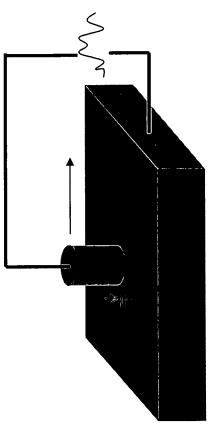
## Vibrating vs. Scanning



Vibrating Probe - Old Technology

Vertical motion (vibration) of the probe produces a time-varying signal at a single location on the surface.

- Slow data acquisition
- Mechanically and electronically complex
- Measures only metallic surfaces

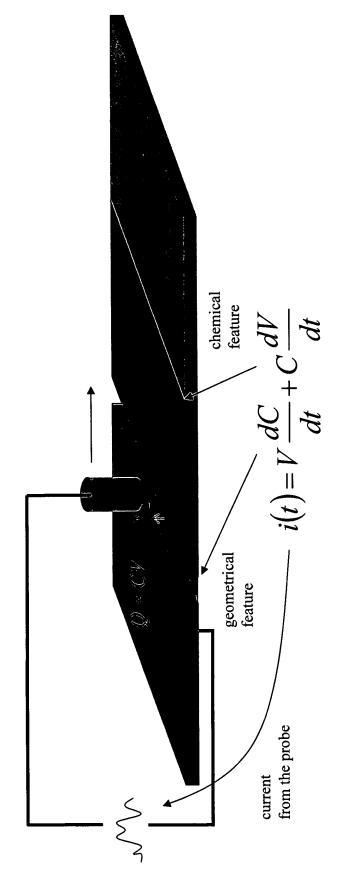


Scanning Probe – New CPD Technology

Motion (scanning) of the probe produces a continuous stream of data along the direction of motion.

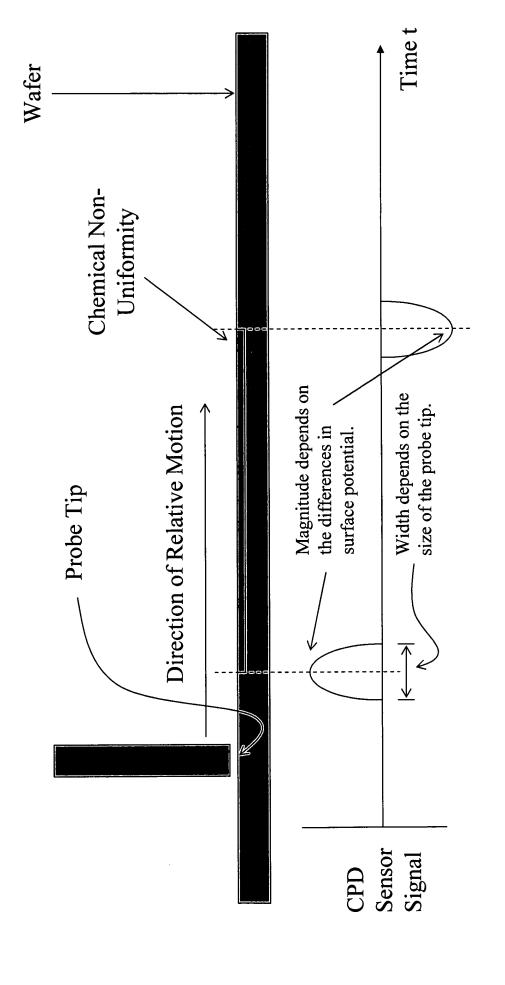
- Fast data acquisition
- Mechanically and electronically simple
- Measures dielectric layers and interfaces

#### CPD Scanning Over Geometric and/or Chemical Features



- Geometric changes across the surface result in changes in capacitance (dC/dt).
- Surface potential (chemistry) changes across the surface result in changes in voltage (dV/dt).
- The sensor produces a signal that is a combination of geometric and surface potential changes across the surface.

## Differential CPD Signal



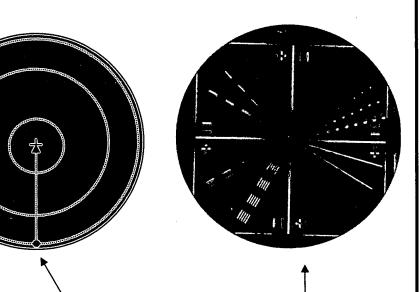
# Example of Scanning Method – Flat

Surfaces

Sample is mounted on vacuum chuck and spindle, and rotated at up to 5000 rpm to create relative motion between sensor and wafer surface.

The probe tip steps along a radius of the wafer, acquiring concentric circles, or "tracks", of data.

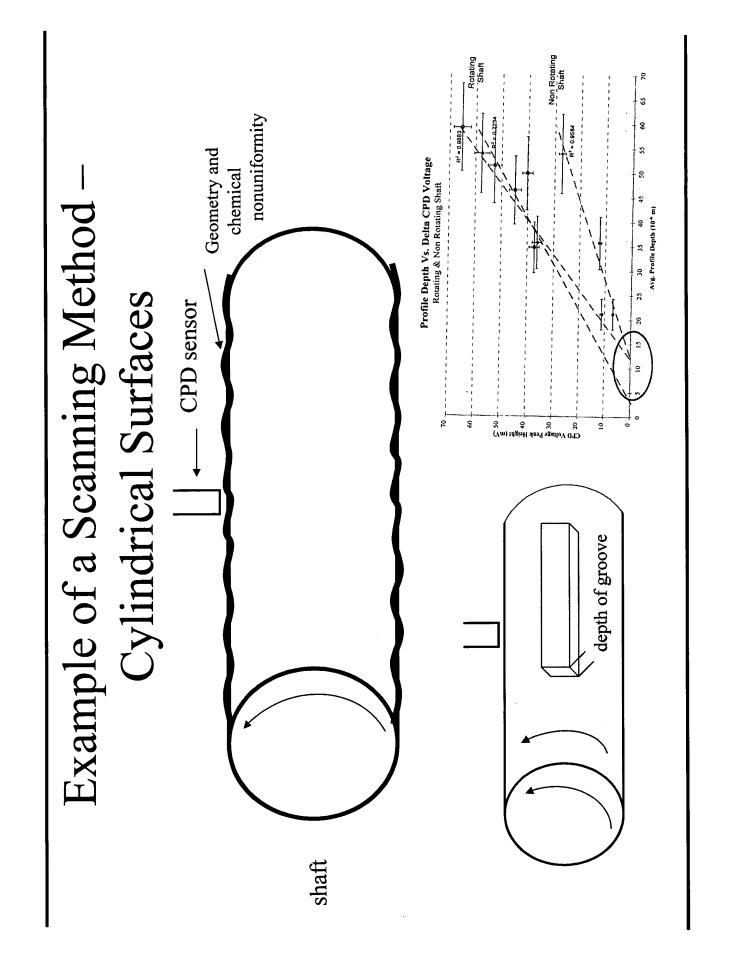
The resulting radial data is displayed as an image representing samples of the voltage output of the sensor.



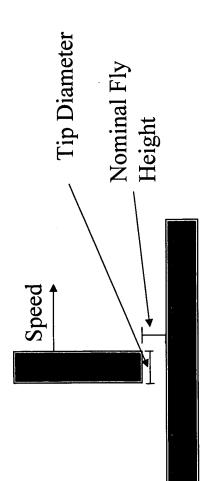
**Patterned** 

Silicon

Wafer



### Scanning Variables



Larger	Increased signal strength	Less probability of wafer contact	Faster scanning speed and increased signal strength	Increased signal-to-noise	Required for improved resolution
Smaller	Improved resolution	Improved resolution and increased signal strength	Better resolution	Faster scanning speed	Less data for display and processing
Typical Values	25 µm to 500 µm	15 µm to 100 µm	250 rpm to 1000 rpm	1 to 10	1000 to 40,000
Variable	Tip Diameter	Nominal Fly Height	Speed	Averaging	Samples / Track

## Important Technical Detail

$$i = C \frac{dV}{dt} + V \frac{dc}{dt}$$
$$dV \rightarrow \frac{dV}{dx} \cdot \frac{dx}{dt}$$
velocity

